## **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Flectronic Version v18

Stylesheet Version v18.0

Title of Invention METHOD AND STRUCTURE OF VERTICAL STRAINED SILICON DEVICES

Application Number :

Confirmation Number:

First Named Applicant: Kangguo Cheng
Attorney Docket Number: FIS920030221US1

Art Unit: Examiner:

Search string: (6313486 or 6503833 or 6524935 or 5461243 or 5847419 or 6429061 or 5256550

).pn

## **US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6313486	2001-11-06	Kencke, et al.			
	2	6503833	2003-01-07	Ajmera, et al.			
	3	6524935	2003-02-25	Canaperi, et al.			
	4	5461243	1995-10-24	Ek, et al.			
	5	5847419	1998-12-08	Imai, et al.			
	6	6429061	2002-08-06	Rim			
	7	5256550	1993-10-26	Laderman, et al.			

## Signature

Examiner Name	Date